Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.300 inches
Overall Diameter:
0.104 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
22.0 breakdown voltage, dc
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air

Test Data Document:

80063-a3012733 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0